

Mayer & Williams, PC
251 North Avenue West. 2nd Floor
Westfield, NJ 07090

RECEIVED
CENTRAL FAX CENTER

NOV 28 2005

Fax Cover Sheet

DATE:	November 28, 2005	PAGES:	<u>8 (eight) w/cover</u>
TO:	Examiner Thao X. Le Art Unit 2814 - USPTO	PHONE:	(571) 272-1708
		FAX:	(571) 273-8300
FROM:	Karin L. Williams Mayer & Williams, PC	PHONE:	(908) 518-7700
		FAX:	(908) 518-7795

Message

Docket No. GS 162 D1

Please see attached: Second Amendment After Final Rejection

CONFIDENTIALITY NOTICE


This facsimile transmission is intended only for the use of the addressee and may contain confidential information which is protected by the attorney/client privilege. If you are not the recipient, you are hereby notified that any disclosure, copying, distribution or the taking of any action in reliance on the contents of this information is strictly prohibited. If you have received this communication in error, please notify us immediately by telephone to arrange for its return.

RECEIVED
CENTRAL FAX CENTERPatent
10/673,889

NOV 28 2005

I hereby certify that this document and any documents referenced herein have been transmitted via facsimile to the Commission for Patents, at (571) 273-8300 on November 28, 2005.

Date:

11/28/05
Karin L. Williams**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Richard A. Blanchard
Serial No.: 10/673,889
Filed: September 29, 2003
Title: High Voltage Power MOSFET Having Low On-Resistance
Art Unit: 2814
Examiner: Thao X. Le
Docket No.: GS 162 Div.
Confirmation No.: 1992

VIA FACSIMILE: 571-273-8300

Commissioner for Patents
PO Box 1450
Alexandria, VA 22313-1450

SECOND AMENDMENT AFTER FINAL REJECTION

Sir:

In further response to the final Office Action dated July 26, 2005, the time for response extended to Monday, November 28, 2005, and in light of the Advisory Action dated November 14, 2005, please consider the following remarks. In addition, any deficiencies may be charged to deposit account No. 50-1047.